

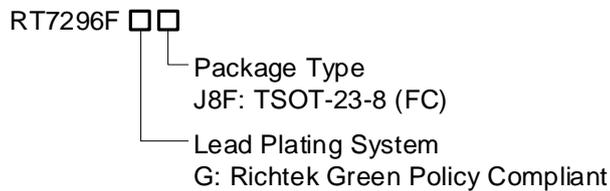
## 3A, 17V Current Mode Synchronous Step-Down Converter

### General Description

The RT7296F is a high-efficiency, 3A current mode synchronous step-down DC-DC converter with a wide input voltage range from 4.5V to 17V. The device integrates 80mΩ high-side and 30mΩ low-side MOSFETs to achieve high efficiency conversion. The current mode control architecture supports fast transient response and internal compensation. The RT7296F provides power good pin to be an output voltage ready indicator. A cycle-by-cycle current limit function provides protection against shorted output. The RT7296F provides complete protection functions such as input undervoltage lockout, output undervoltage protection, overcurrent protection, and thermal shutdown. The PWM frequency is adjustable by the EN/SYNC pin. The RT7296F is available in the TSOT-23-8 (FC) package.

The recommended junction temperature range is -40°C to 125°C and ambient temperature range is -40°C to 85°C.

### Ordering Information



Note:

Richtek products are Richtek Green Policy compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.

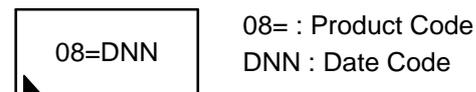
### Features

- 4.5V to 17V Input Voltage Range
- 3A Output Current
- Internal N-Channel MOSFETs
- Current Mode Control
- Fixed Switching Frequency: 500kHz
- Synchronous to External Clock: 200kHz to 2MHz
- Cycle-by-Cycle Current Limit
- Internal Soft-Start Function
- Power Saving Mode at Light Load
- Power Good Indicator
- Input Undervoltage Lockout
- Output Undervoltage Protection
- Thermal Shutdown
- RoHS Compliant and Halogen Free

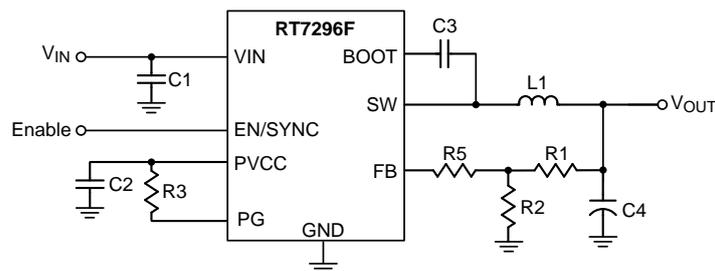
### Applications

- Industrial and Commercial Low Power Systems
- Computer Peripherals
- LCD Monitors and TVs
- Set-top Boxes

### Marking Information

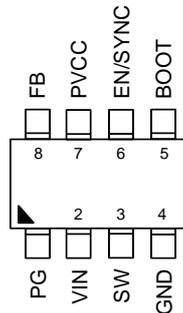


### Simplified Application Circuit



## Pin Configuration

(TOP VIEW)

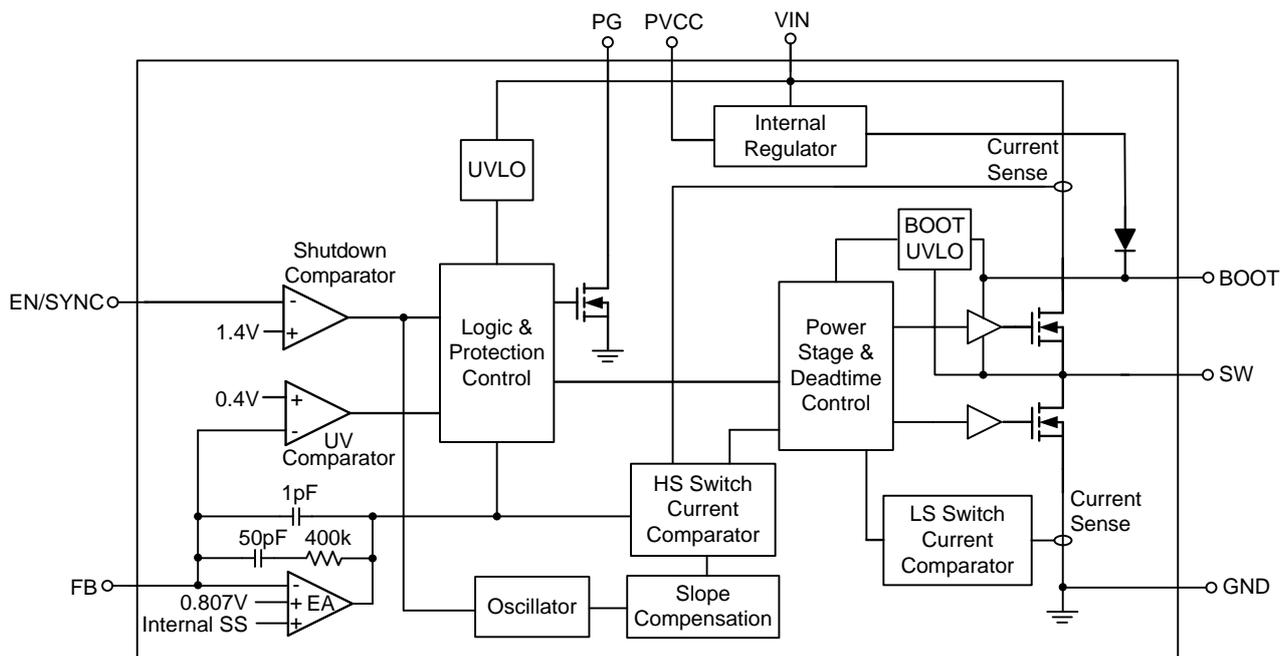


TSOT-23-8 (FC)

## Functional Pin Description

Pin No.	Pin Name	Pin Function
1	PG	Power good output. This pin is an open drain which can be connected to PVCC by a resistor. If output voltage achieve 90% of the normal voltage, the PG pin will go high after 400 $\mu$ s delay.
2	VIN	Power input. Support 4.5V to 17V Input Voltage. Must bypass with a ceramic capacitor at this pin.
3	SW	Switch node. Connect to external L-C filter.
4	GND	System ground.
5	BOOT	Bootstrap supply for high-side gate driver. Connect a 0.1 $\mu$ F ceramic capacitor between the BOOT and SW pins.
6	EN/SYNC	Enable control input. High = Enable. Apply an external clock to adjust the switching frequency. If using pull high resistor connected to VIN, the recommended value range is 60k $\Omega$ to 300k $\Omega$ .
7	PVCC	5V Bias supply output. Connect a minimum of 0.1 $\mu$ F capacitor to ground.
8	FB	Feedback voltage input. The pin is used to set the output voltage of the converter to regulate to the desired voltage via a resistive divider. Feedback reference = 0.807V.

## Functional Block Diagram



## Operation

### Power Saving Mode

The RT7296F automatically enters into power saving mode (PSM) at light load to improve efficiency. In PSM, the RT7296F disables the internal CLK when  $V_{FB}$  is above the  $V_{REF} \times 1.005$  (typ.). In other words, the device automatically skips the PWM pulse at light load. While  $V_{FB}$  falls below the  $V_{REF} \times 1.005$ , the RT7296F enables the internal CLK again and hence the new switching cycle is activated. When the internal switches are activated, for each cycle the device detects the peak inductor current ( $I_{L\_PEAK}$ ) and keeps high-side switch on until the  $I_L$  reaches its minimum peak current level (as shown in Figure 1). When low-side switch is turn-on, the zero-current detection is also activated to prevent that  $I_L$  becomes negative and enables the higher efficiency at light load. During the period that both switches are off, the device turns off the most of the internal circuit to reduce the quiescent power consumption further.

With lower output loading, the non-switching period is longer, so the effective switching frequency becomes lower to reduce the switching loss and switch driving loss.

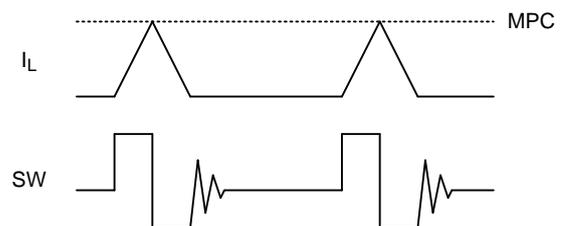


Figure 1. Minimum Peak Current at PSM

### Power Good Indication

The RT7296F features an open-drain power-good output (PG) to monitor the output voltage status. Connect PG to PVCC or an external voltage below 5.5V with a resistor. The power-good function is activated after soft-start is finished and is controlled by a comparator connected to the feedback signal  $V_{FB}$ . If  $V_{FB}$  rises above a power-good high threshold ( $PG_{Vth\_Hi}$ , typically 90% of the reference voltage), the PG pin will be in high impedance and  $V_{PG}$  will be held high after a certain delay elapsed (typically, 400 $\mu$ s). When  $V_{FB}$  falls short of power good low threshold ( $PG_{Vth\_Lo}$ , typically 85% of the reference voltage), the PG pin will be pulled low.

## Undervoltage Lockout Threshold

The IC includes an input Undervoltage Lockout Protection (UVLO). If the input voltage exceeds the UVLO rising threshold voltage (3.9V), the converter resets and prepares the PWM for operation. If the input voltage falls below the UVLO falling threshold voltage (3.25V) during normal operation, the device stops switching. The UVLO rising and falling threshold voltage includes a hysteresis to prevent noise caused reset.

## Chip Enable

The EN pin is the chip enable input. Pulling the EN pin low (<1.1V) will shutdown the output voltage. During shutdown mode (<0.4V), the RT7296F's quiescent current drops to lower than 1 $\mu$ A. Driving the EN pin high (>1.6V) will turn on the device.

## Operating Frequency and Synchronization

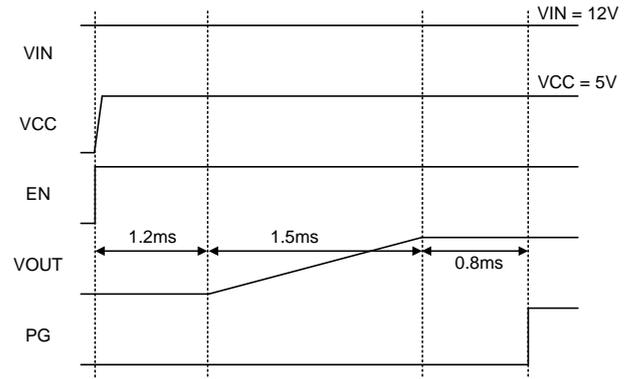
The internal oscillator runs at 500kHz (typ.) when the EN/SYNC pin is at logic-high level (>1.6V). If the EN pin is pulled to low-level over 8 $\mu$ s, the IC will shut down. The RT7296F can be synchronized with an external clock ranging from 200kHz to 2MHz applied to the EN/SYNC pin. The external clock duty cycle must be from 20% to 80% with logic-high level = 2V and logic-low level = 0.8V.

## Internal Regulator

The internal regulator generates 5V power and drive internal circuit. When VIN is below 5V, PVCC will drop with VIN. A capacitor (>0.1 $\mu$ F) between PVCC and GND is required.

## Internal Soft-Start Function

The RT7296F provides internal soft-start function. The soft-start function is used to prevent large inrush current while converter is being powered-up. Output voltage starts to rise 1.2ms after EN rising, and the soft-start time ( $V_{FB}$  from 0V to 0.8V) is 1.5ms. PG signal goes high 0.8ms after completing soft-start.



## High-Side MOSFET Overcurrent Limit

The RT7296F features cycle-by-cycle current-limit protection and prevents the device from the catastrophic damage in output short circuit, overcurrent or inductor saturation. During the on-time of the high side switch, the device monitors the switch current. If the switch current overs the current-limit threshold, the device turns off the high side switch to prevent the device from damage.

## Output Undervoltage Protection

The RT7296F includes output undervoltage protection (UVP) against over-load or short-circuited condition by constantly monitoring the feedback voltage  $V_{FB}$ . If  $V_{FB}$  drops below the undervoltage protection trip threshold, 50% (typ.) of the internal reference voltage, the UV comparator will go high to turn off the internal high-side MOSFET switches. If the output undervoltage condition continues for a period of time, the RT7296F will enter output undervoltage protection with hiccup mode. During hiccup mode, the device remains shut down. After a period of time, a soft-start sequence for auto-recovery will be initiated. Upon completion of the soft-start sequence, if the fault condition is removed, the converter will resume normal operation; otherwise, such cycle for auto-recovery will be repeated until the fault condition is cleared. Hiccup mode allows the circuit to operate safely with low input current and power dissipation, and then resume normal operation as soon as the over-load or short-circuit condition is removed. The UVP profile is shown in Figure 2.

**Over-Temperature Protection**

Over-temperature protection is implemented to prevent the chip from operating at excessively high temperatures. When the junction temperature is higher than 150°C, the OTP will shut down switching operation. The chip will automatically resume normal operation with a complete soft-start sequence once the junction temperature cools down by approximately 20°C.

**BOOT UVLO**

The RT7296F implements BOOT UVLO function to ensure the VBOOT-SW is sufficient to correctly activate the high side switch at any condition. BOOT UVLO usually activates at higher VOUT, very light load and small TTH threshold. With such conditions, the low side switch may not have sufficient turn-on time to charge the BOOT capacitor. The BOOT UVLO activates when VBOOT-SW is lower than 2.65V (typ.), the device will be forced to turn on the low side switch for 200ns (typ.) to charge the BOOT capacitor. The BOOT UVLO behavior continues for each PWM cycle until the VBOOT-SW is higher than 2.9V (typ.)

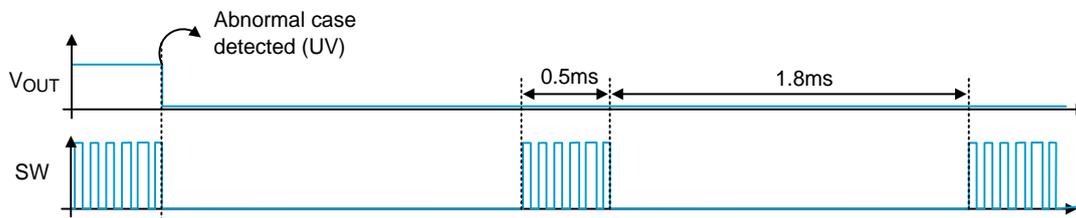


Figure 2. Output Undervoltage Protection with Hiccup Mode

## Absolute Maximum Ratings (Note 1)

- Supply Input Voltage, VIN ----- -0.3V to 20V
- Switch Voltage, SW ----- -0.3V to 20.3V
  - <10 $\mu$ s ----- -1V to 20.3V
  - <100ns ----- -5V to 25V
- BOOT to SW, VBOOT – SW ----- -0.3V to 6V (7V for < 10 $\mu$ s)
- Bias Supply Output, PVCC ----- -0.3V to 6V (7V for < 10 $\mu$ s)
- Other Pins ----- -0.3V to 6V
- Power Dissipation, PD @ TA = 25°C
  - TSOT-23-8 (FC) ----- 1.428W
- Package Thermal Resistance (Note 2)
  - TSOT-23-8 (FC),  $\theta_{JA}$  ----- 70°C/W
  - TSOT-23-8 (FC),  $\theta_{JC}$  ----- 15°C/W
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Junction Temperature ----- -40°C to 150°C
- Storage Temperature Range ----- -65°C to 150°C
- ESD Susceptibility (Note 3)
  - HBM (Human Body Model) ----- 2kV

## Recommended Operating Conditions (Note 4)

- Supply Input Voltage, VIN ----- 4.5V to 17V
- Junction Temperature Range ----- -40°C to 125°C
- Ambient Temperature Range ----- -40°C to 85°C

## Electrical Characteristics

(VIN = 12V, TA = 25°C, unless otherwise specified)

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Shutdown Supply Current			VEN = 0V	--	7	--	$\mu$ A
Quiescent Current with no Load at DCDC Output			VEN = 2V, VFB = 1V	--	0.8	1	mA
Feedback Voltage		VFB		0.799	0.807	0.815	V
Feedback Current		IFB	VFB = 820mV	--	10	50	nA
Switch On-Resistance	High-Side	RDS(ON)H		--	80	--	m $\Omega$
	Low-Side	RDS(ON)L		--	30	--	
Switch Leakage			VEN = 0V, VSW = 0V	--	--	1	$\mu$ A
Current Limit		ILIM	Under 40% duty-cycle	4.2	5	5.8	A
Low-Side Switch Current Limit			From drain to source	--	2	--	A
Oscillation Frequency		fOSC	VFB = 0.75V	440	500	570	kHz
SYNC Frequency Range		fSYNC		200	--	2000	kHz
Fold-Back Frequency			VFB < 400mV	--	125	--	kHz

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Maximum Duty-Cycle		D <sub>MAX</sub>	V <sub>FB</sub> = 0.7V	90	95	--	%
Minimum On-Time		t <sub>ON</sub>		--	60	--	ns
EN Input Voltage	Logic-High	V <sub>IH</sub>		1.2	1.4	1.6	V
	Logic-Low	V <sub>IL</sub>		1.1	1.25	1.4	
EN Input Current		I <sub>EN</sub>	V <sub>EN</sub> = 2V	--	2	--	μA
			V <sub>EN</sub> = 0V	--	0	--	
EN Turn-off Delay		EN <sub>td-off</sub>		--	8	--	μs
Power-Good Rising Threshold		PG <sub>vth-Hi</sub>		--	0.9	--	V <sub>FB</sub>
Power-Good Falling Threshold		PG <sub>vth-Lo</sub>		--	0.85	--	V <sub>FB</sub>
Power-Good Delay		PG <sub>Td</sub>		--	0.4	--	ms
Power-Good Sink Current Capability		V <sub>PG</sub>	Sink 4mA	--	--	0.4	V
Power-Good Leakage Current		IPG-LEAK		--	--	1	μA
Input Undervoltage Lockout Threshold	V <sub>IN</sub> Rising	V <sub>UVLO</sub>	V <sub>IN</sub> rising	3.7	3.9	4.1	V
	Hysteresis	ΔV <sub>UVLO</sub>		--	650	--	mV
PVCC Regulator		V <sub>CC</sub>		--	5	--	V
PVCC Load Regulation		ΔV <sub>LOAD</sub>	I <sub>VCC</sub> = 5mA	--	3	--	%
Soft-Start Time		t <sub>SS</sub>	FB from 0V to 0.8V	--	1.5	--	ms
Thermal Shutdown Temperature		T <sub>SD</sub>		--	150	--	°C
Thermal Shutdown Hysteresis		ΔT <sub>SD</sub>		--	20	--	°C

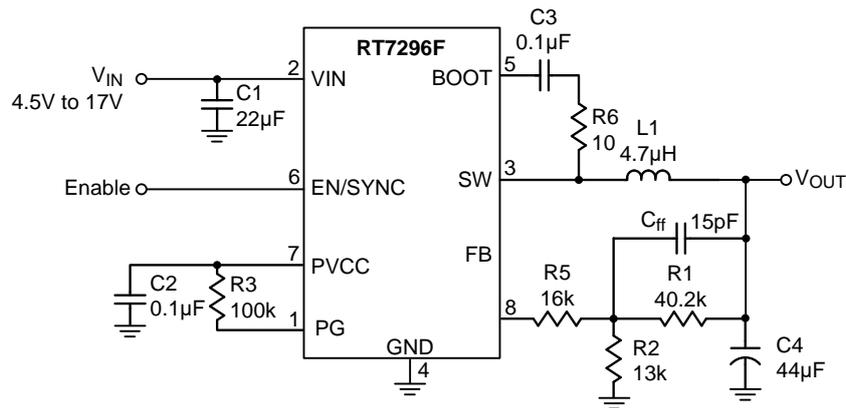
**Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

**Note 2.** θ<sub>JA</sub> is measured in the natural convection at T<sub>A</sub> = 25°C on a four-layer Richtek Evaluation Board. θ<sub>JC</sub> is measured at the lead of the package.

**Note 3.** Devices are ESD sensitive. Handling precaution recommended.

**Note 4.** The device is not guaranteed to function outside its operating conditions.

## Typical Application Circuit

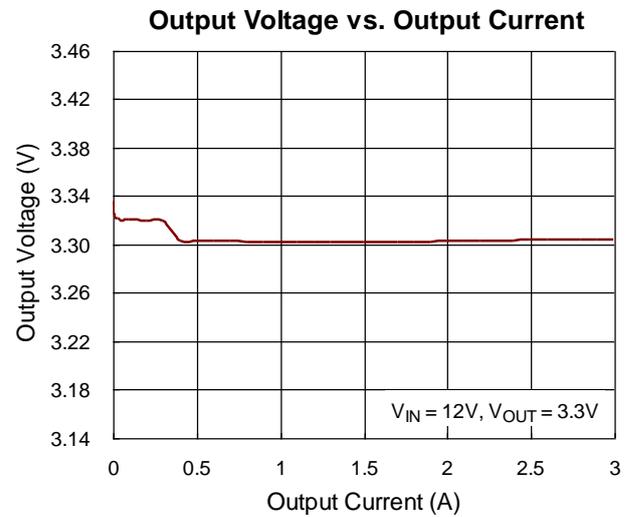
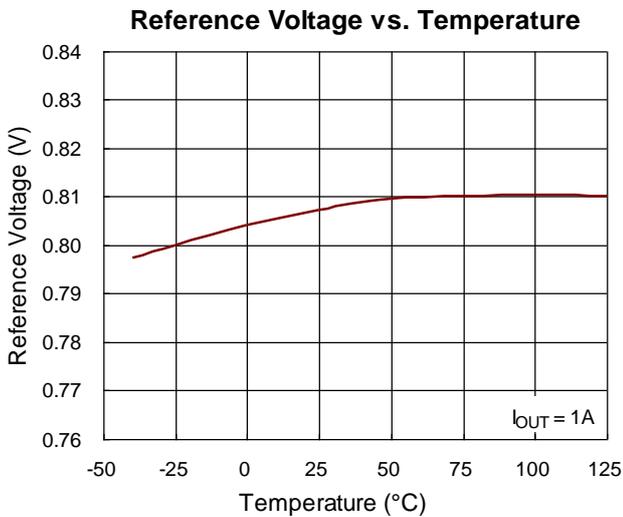
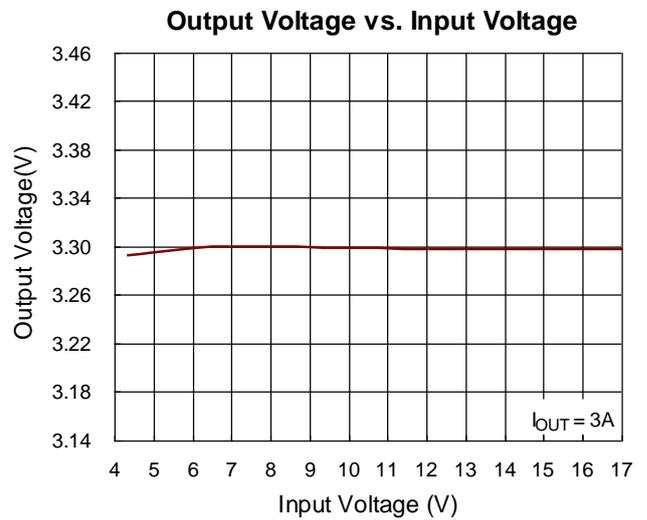
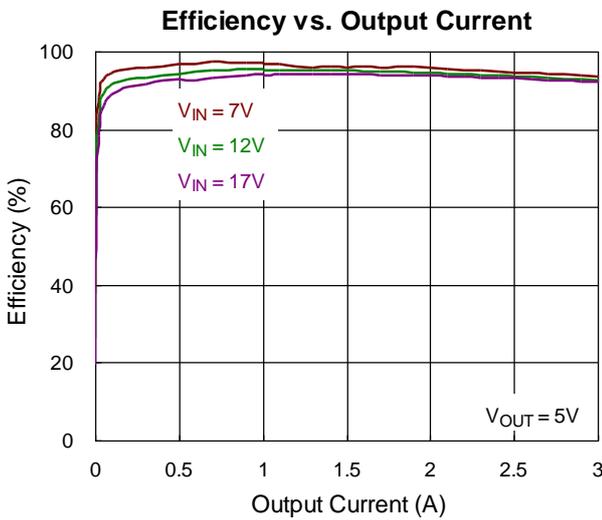
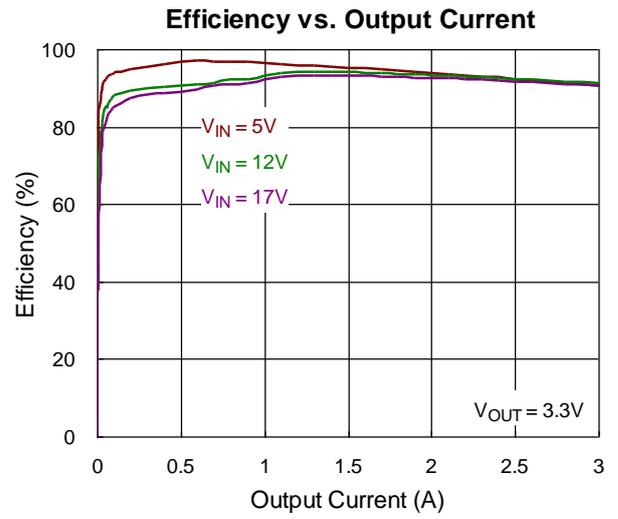
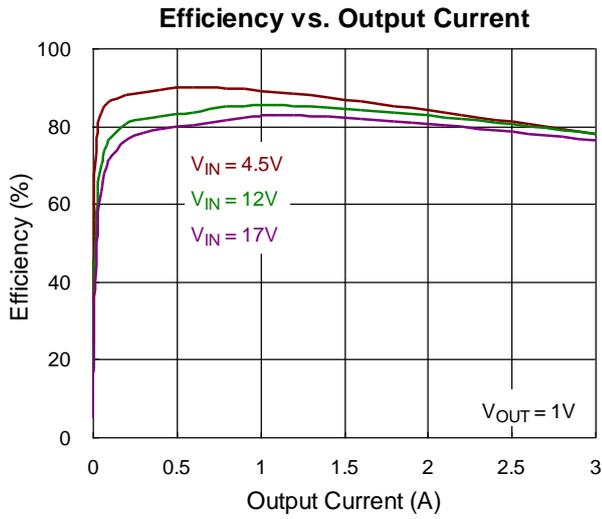


**Table 1. Suggested Component Values**

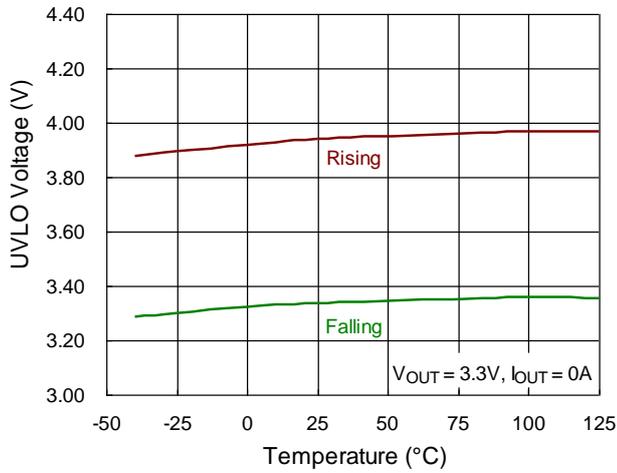
V <sub>OUT</sub> (V)	R1 (kΩ)	R2 (kΩ)	R5 (kΩ)	C <sub>ff</sub> (pF)	C2 (µF)	C4 (µF)	L1 (µH)
1.0	20.5	84.5	82	15	0.1	44	2.2
3.3	40.2	13	16	15	0.1	44	4.7
5.0	40.2	7.68	16	15	0.1	44	4.7

Note: Where the C4 value means the effective output capacitance. Design engineer must be aware that ceramic capacitance varies a great deal with the size, operating voltage and temperature. The variation should be taken into the design consideration of control loop bandwidth. A rule-of-the-thumb is to design the RT7296F control loop bandwidth below 60kHz by changing the value of R5. Generally, increase the value of R5 if a de-rated capacitance is used.

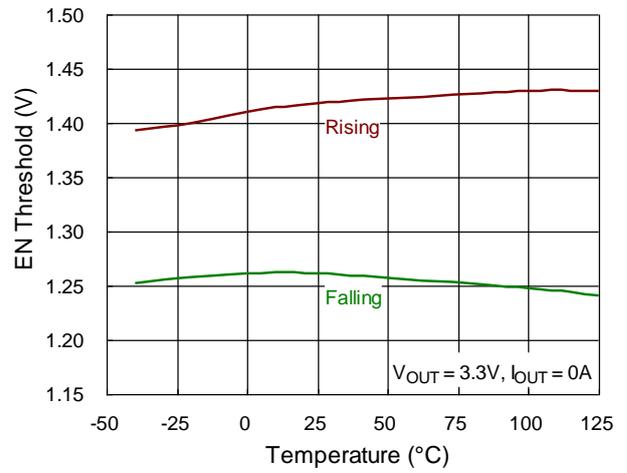
Typical Operating Characteristics



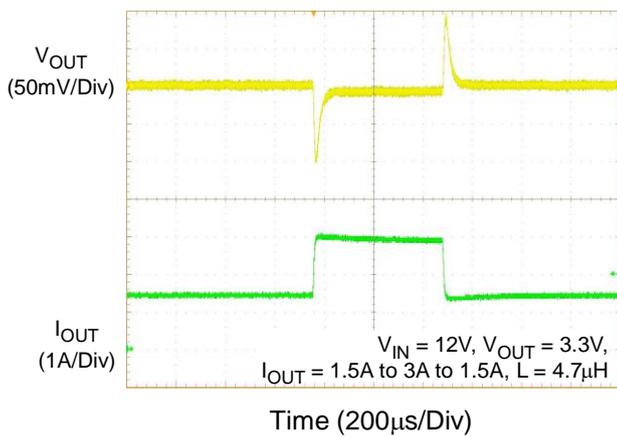
### UVLO Voltage vs. Temperature



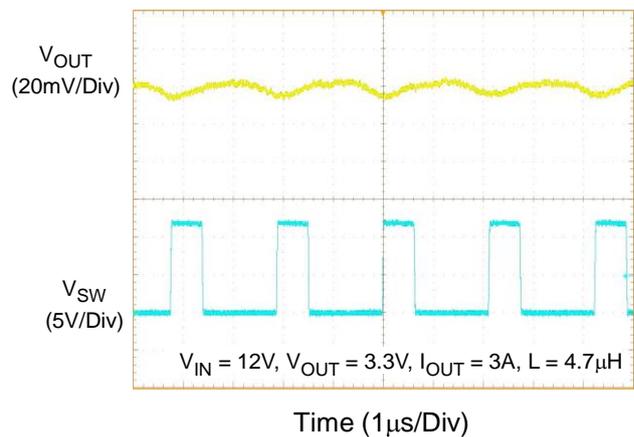
### EN Threshold vs. Temperature



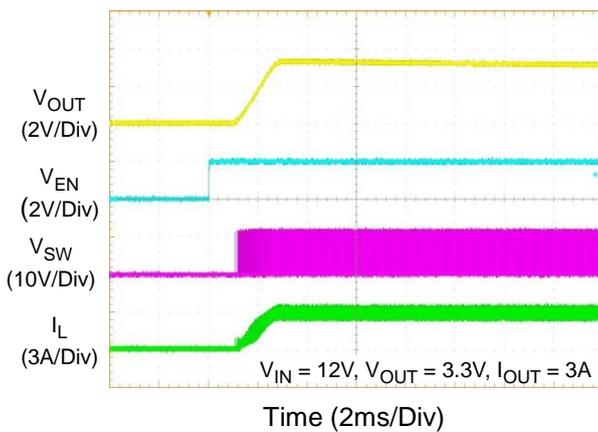
### Load Transient Response



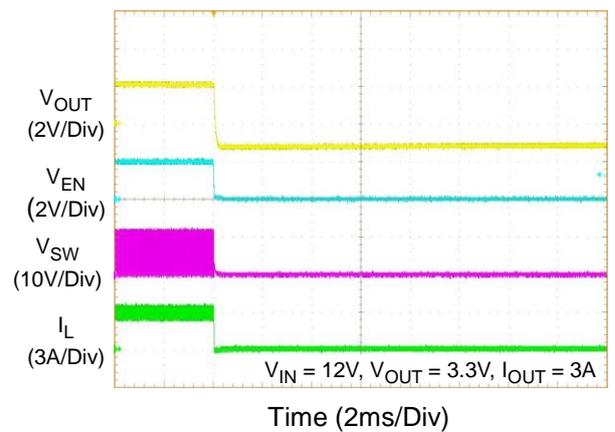
### Output Ripple Voltage



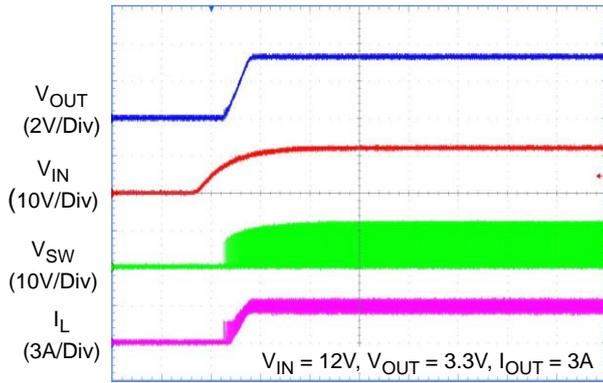
### Power On from EN



### Power Off from EN

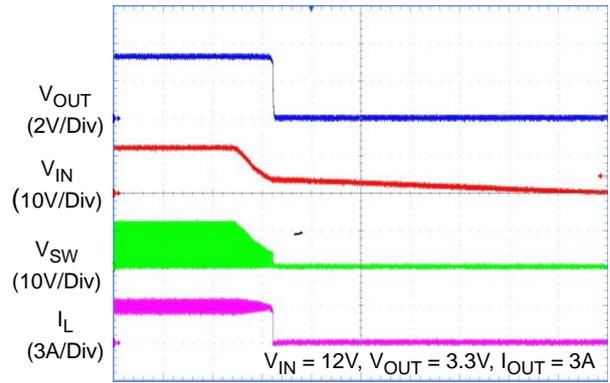


**Power On from VIN**



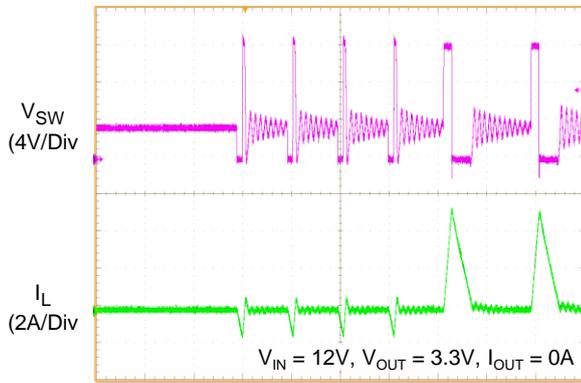
Time (5ms/Div)

**Power Off from VIN**



Time (5ms/Div)

**BOOT UVLO**



Time (2μs/Div)

## Application Information

**Richtek's component specification does not include the following information in the Application Information section. Thereby no warranty is given regarding its validity and accuracy. Customers should take responsibility to verify their own designs and reserve suitable design margin to ensure the functional suitability of their components and systems.**

The RT7296F is a high voltage buck converter that can support the input voltage range from 4.5V to 17V and the output current can be up to 3A.

### Output Voltage Selection

The resistive voltage divider allows the FB pin to sense a fraction of the output voltage as shown in Figure 3.

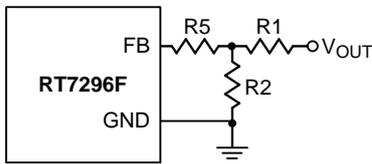


Figure 3. Output Voltage Setting

For adjustable voltage mode, the output voltage is set by an external resistive voltage divider according to the following equation:

$$V_{OUT} = V_{FB} \left( 1 + \frac{R1}{R2} \right)$$

Where  $V_{FB}$  is the feedback reference voltage (0.8V typ.). Table 2 lists the recommended resistors value for common output voltages.

Table 2. Recommended Resistors Value

V <sub>OUT</sub> (V)	R1 (kΩ)	R2 (kΩ)	R5 (kΩ)
1.0	20.5	84.5	82
3.3	40.2	13	16
5.0	40.2	7.68	16

### External Bootstrap Diode

Connect a 100nF low ESR ceramic capacitor between the BOOT pin and SW pin. This capacitor provides the gate driver voltage for the high-side MOSFET. It is recommended to add an external bootstrap diode between an external 5V and BOOT pin, as shown as Figure 4, for efficiency improvement when input voltage

is lower than 5.5V or duty ratio is higher than 65%. The bootstrap diode can be a low cost one such as IN4148 or BAT54. The external 5V can be a 5V fixed input from system or a 5V output (PVCC) of the RT7296F.

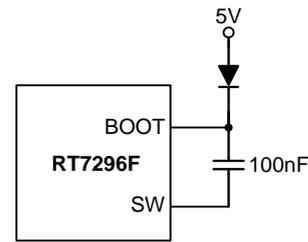


Figure 4. External Bootstrap Diode

### Inductor Selection

The inductor value and operating frequency determine the ripple current according to a specific input and output voltage. The ripple current  $\Delta I_L$  increases with higher  $V_{IN}$  and decreases with higher inductance.

$$\Delta I_L = \left( \frac{V_{OUT}}{f \times L} \right) \times \left( 1 - \frac{V_{OUT}}{V_{IN}} \right)$$

Having a lower ripple current reduces not only the ESR losses in the output capacitors but also the output voltage ripple. High frequency with small ripple current can achieve highest efficiency operation. However, it requires a large inductor to achieve this goal.

For the ripple current selection, the value of  $\Delta I_L = 0.3 (I_{MAX})$  will be a reasonable starting point. The largest ripple current occurs at the highest  $V_{IN}$ . To guarantee that the ripple current stays below the specified maximum, the inductor value should be chosen according to the following equation:

$$L = \left( \frac{V_{OUT}}{f \times \Delta I_L(MAX)} \right) \times \left( 1 - \frac{V_{OUT}}{V_{IN(MAX)}} \right)$$

The inductor's current rating (caused a 40°C temperature rising from 25°C ambient) should be

greater than the maximum load current and its saturation current should be greater than the short circuit peak current limit.

**C<sub>IN</sub> and C<sub>OUT</sub> Selection**

The input capacitance, C<sub>IN</sub>, is needed to filter the trapezoidal current at the source of the top MOSFET. To prevent large ripple current, a low ESR input capacitor sized for the maximum RMS current should be used. The RMS current is given by:

$$I_{RMS} = I_{OUT(MAX)} \frac{V_{OUT}}{V_{IN}} \sqrt{\frac{V_{IN}}{V_{OUT}} - 1}$$

This formula has a maximum at V<sub>IN</sub> = 2V<sub>OUT</sub>, where I<sub>RMS</sub> = I<sub>OUT</sub>/2. This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief.

Choose a capacitor rated at a higher temperature than required. Several capacitors may also be paralleled to meet size or height requirements in the design. The selection of C<sub>OUT</sub> is determined by the required Effective Series Resistance (ESR) to minimize voltage ripple. Moreover, the amount of bulk capacitance is also a key for C<sub>OUT</sub> selection to ensure that the control loop is stable. Loop stability can be checked by viewing the load transient response as described in a later section. The output ripple, ΔV<sub>OUT</sub>, is determined by:

$$\Delta V_{OUT} \leq \Delta I_L \times \left( ESR + \frac{1}{8fC_{OUT}} \right)$$

The output ripple will be highest at the maximum input voltage since ΔI<sub>L</sub> increases with input voltage. Multiple capacitors placed in parallel may be needed to meet the ESR and RMS current handling requirement. Dry tantalum, special polymer, aluminum electrolytic and ceramic capacitors are all available in surface mount packages. Special polymer capacitors offer very low ESR value. However, it provides lower capacitance density than other types. Although Tantalum capacitors have the highest capacitance density, it is important to only use types that pass the surge test for use in

switching power supplies. Aluminum electrolytic capacitors have significantly higher ESR. However, it can be used in cost-sensitive applications for ripple current rating and long term reliability considerations. Ceramic capacitors have excellent low ESR characteristics but can have a high voltage coefficient and audible piezoelectric effects. The high Q of ceramic capacitors with trace inductance can also lead to significant ringing.

**Thermal Considerations**

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where T<sub>J(MAX)</sub> is the maximum junction temperature, T<sub>A</sub> is the ambient temperature, and θ<sub>JA</sub> is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ<sub>JA</sub>, is layout dependent. For TSOT-23-8 (FC) package, the thermal resistance, θ<sub>JA</sub>, is 70°C/W on a standard four-layer thermal test board. The maximum power dissipation at T<sub>A</sub> = 25°C can be calculated by the following formula:

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (70^\circ\text{C/W}) = 1.428\text{W for TSOT-23-8 (FC) package}$$

The maximum power dissipation depends on the operating ambient temperature for fixed T<sub>J(MAX)</sub> and thermal resistance, θ<sub>JA</sub>. The derating curve in Figure 5 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

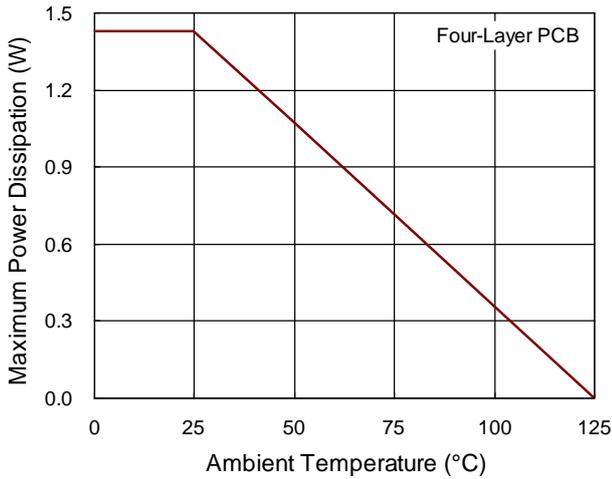


Figure 5. Derating Curve of Maximum Power Dissipation

**Layout Considerations**

For best performance of the RT7296F, the following layout guidelines must be strictly followed.

- ▶ Input capacitor must be placed as close to the IC as possible.
- ▶ SW should be connected to inductor by wide and short trace. Keep sensitive components away from this trace.
- ▶ Keep VIN, GND and SW traces connected to pin as wide as possible for improving thermal dissipation.

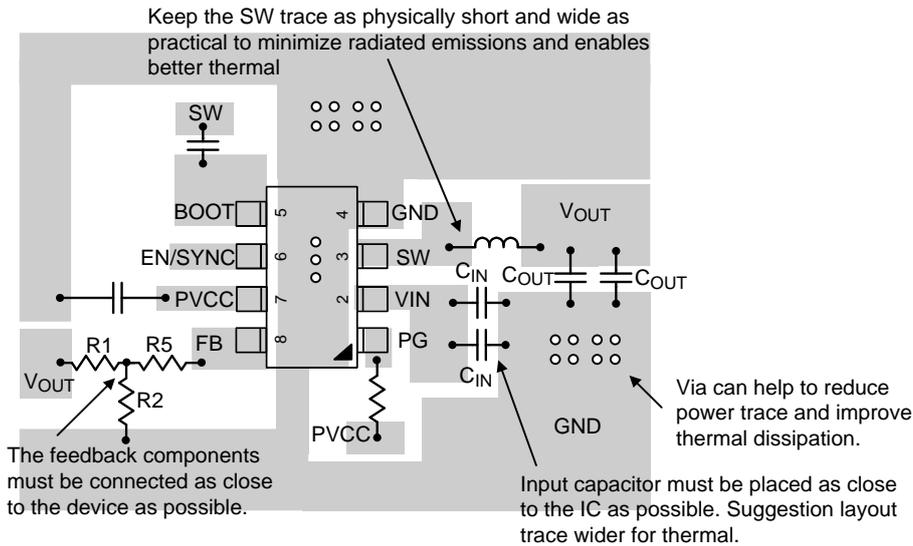
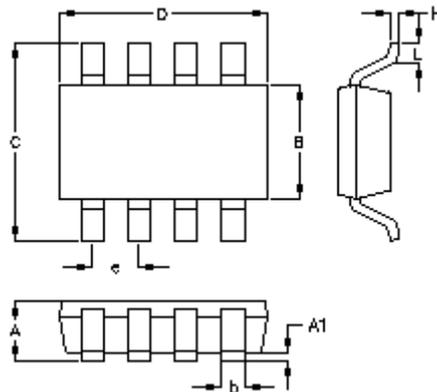


Figure 6. PCB Layout Guide

**Outline Dimension**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	1.000	0.028	0.039
A1	0.000	0.100	0.000	0.004
B	1.397	1.803	0.055	0.071
b	0.220	0.380	0.009	0.015
C	2.591	3.000	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.585	0.715	0.023	0.028
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

**TSOT-23-8 (FC) Surface Mount Package**

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## Datasheet Revision History

Version	Date	Description	Item
06	2023/9/25	Modify	Absolute Maximum Ratings on P6 Application Information on P12